

#### **General Description**

This single 2-input exclusive-OR gate is designed for 1.65V to 5.5V  $V_{\text{CC}}$  operation.

The SN74LVC1G86 performs the Boolean function Y=A⊕B or Y=ĀB+AB in positive logic. A common application is as a true/complement element. If the input is low, the other

input is reproduced in true form at the output. If the input is high, the signal on the other input is reproduced inverted at the output.

This device is fully specified for partial-power-down applications using  $l_{\text{off}}$ . The  $l_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### **Features**

- Operate from 1.65 V to 5.5 V
- Specified from -40°C to 125°C
- Inputs accept voltages to 5.5V
- Max t<sub>pd</sub> of 3.7ns at 3.3V

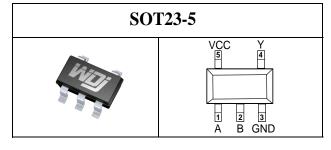
- Low power consumption, 10µA max lcc
- ±24-mA output drive at 3.3V
- loff supports partial-power-down mode

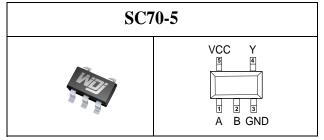
# **Applications**

- Wireless headsets
- Motor drives and controls
- TVs

- Set-top boxes
- Audio

# **Pinning and Package**

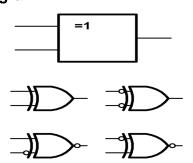




#### **Order information**

Package	Orderable Device	Packing Option
SOT23-5	SN74LVC1G86DBVRW	3000/盘
SC70-5	SN74LVC1G86DCKRW	3000/蓝

# **Circuit Diagram**





#### **Pin Functions**

Piı	n	Typo	Description
Name	SOT23-5/SC70-5	Туре	Description
А	1	I	Input A
В	2	I	Input B
Υ	4	0	Output Y
VCC	5	-	Positive Supply
GND	3	-	Ground

# **Absolute Maximum Ratings**

	Parameter	Min	Max.	Unit	
Vcc	Supply volt	age range	-0.5	6.5	V
VI	Input volta	ige range	-0.5	6.5	V
Vo	Voltage range applied to any output in the high-impedance or power-off state			6.5	V
Vo	Voltage range applied to any output in the high or low state			V <sub>CC</sub> +0.5	V
Iĸ	Input clamp current	V<0		-50	mA
Іок	Output clamp current	Vo<0		-50	mΑ
lo	Continuous o	utput current		±50	mA
	Continuous current throu		±100	mA	
TJ	Junction temperature under bias			150	°C
T <sub>stg</sub>	Storage temp	erature range	-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# **ESDRatings**

ESD				
V(ESD)	Electrostatio discharge	Human-body model (HBM)	8 K	V
	Electrostatic discharge	Charged-device model (CDM)	1.25 K	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



# **Recommended Operating Conditions**

Over operating free-air temperature range (unless otherwise noted)

Symbol	Para	Min.	Max.	Unit	
Vcc	Supply	1.65	5.5	V	
		V <sub>CC</sub> =1.65V to1.95V	0.65×Vcc		
.,	Library Laurent Marker and	V <sub>CC</sub> =2.3V to 2.7V	1.7		V
V <sub>IH</sub>	High-Level Input Voltage	V <sub>CC</sub> =3V to 3.6V	2		\ \
		V <sub>CC</sub> =4.5V to 5.5V	0.7×V <sub>CC</sub>		
		Vcc=1.65V to1.95V		0.35×V <sub>CC</sub>	
\/	Lave Lavellen AVallana	V <sub>CC</sub> =2.3V to 2.7V		0.7	.,
V <sub>L</sub>	Low-Level Input Voltage	V <sub>CC</sub> =3V to 3.6V		0.8	V
		V <sub>CC</sub> =4.5V to 5.5V		0.3×Vcc	
Vı	Input	0	5.5	V	
Vo	Outpu	t Voltage	0	Vcc	V
		V <sub>CC</sub> =1.65V		-4	
		Vcc=2.3V		-8	
Іон	High-Level Output Current	V 0V		-16	mA
		Vcc=3V		-24	1
		Vcc=4.5V		-32	
		V <sub>CC</sub> =1.65V		4	
		Vcc=2.3V		8	
loL	Low-Level Output Current	\/ -2\/		16	mA
		V <sub>CC</sub> =3V		24	
		V <sub>CC</sub> =4.5V		32	
		V <sub>CC</sub> =1.8V±0.15V,2.5V±0.2V		20	
Δt/Δν	Input Transition Rise or Fall Rate	V <sub>CC</sub> =3.3V±0.3V		10	ns/V
		V <sub>CC</sub> =5V±0.5V		5	
TA	Operating Free-air Temperature	All Other Packages	40	125	°C

<sup>(1)</sup> All unused digital inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation.



# **Electrical Characteristics**

FULL=-40°C to +125°C, Typical values are at TA=+25°C. (unless otherwise noted)

Parameters	Symbol	Conditions	Vcc	TA	Min.	Тур.	Max.	Unit
	"	Outpu	t	, I	J.		JI.	
		I <sub>OH</sub> =–100μA	1.65V to 5.5V		Vcc-0.1			
		I <sub>OH</sub> =–4mA	1.65		1.2			
High Lovel Output Voltage	\ \/.	I <sub>OH</sub> =-8mA	2.3	FULL	1.9			V
High-Level Output Voltage	V <sub>OH</sub> —	I <sub>OH</sub> =-16mA	2	FULL	2.4			- v
		I <sub>OH</sub> =-24mA	3		2.3			
		I <sub>OH</sub> =–32mA	4.5		3.8			
		I <sub>OL</sub> =100μA	1.65V to 5.5V				0.1	- V
		I <sub>OL</sub> =4mA	1.65	- FULL			0.45	
Lave Laval Outrot Valtage	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	I <sub>OL</sub> =8mA	2.3				0.3	
Low-Level Output Voltage	VoL	I <sub>OL</sub> =16mA	2				0.4	
		I <sub>OL</sub> =24mA	3				0.55	
		I <sub>OL</sub> =32mA	4.5				0.55	
Off-State Current	loff	V₁ or V₀=5.5V	0V	FULL			±10	μA
		Input						
Input Leakage Current	lı	A or B input, V <sub>I</sub> =5.5V or GND	0V to 5.5V	FULL			±5	μA
Input Capacitance	Ci	V <sub>I</sub> =V <sub>CC</sub> or GND	3.3V	FULL		6		pF
		Power Su	pply					
Power Supply Range V <sub>CC</sub>			1.65V to 5.5V	FULL	1.65		5.5	V
Supply Current	lœ	V <sub>I</sub> =5.5 V or GND, I <sub>0</sub> =0	1.65V to 5.5V	FULL			10	μA
		One Input at V <sub>CC</sub> – 0.6 V, Other Inputs at V <sub>CC</sub> or GND	3V to 5.5V	FULL			500	μA

<sup>(1)</sup> All unused digital inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation.

# **Switching Characteristics**

Over recommended operating free-air temperature range, C<sub>L</sub>=30pF or 50 pF (unless otherwise noted)

				-40°C to +125°C					
Parameter	From(Input)	To(Output)	Vcc=1.8	3V±0.15V	V <sub>CC</sub> =2.	5V±0.2V	Vcc=3.	3V±0.3V	Units
			Min	Max	Min	Max	Min	Max	
t <sub>pd</sub>	A or B	Υ	2.1	10	1	4.9	0.6	3.7	ns

# **Operating Characteristics**

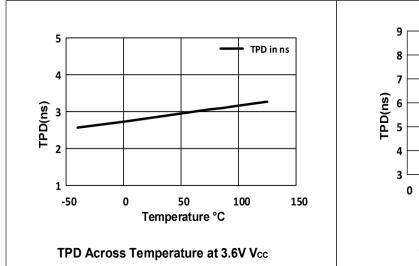
TA=-40°C to +125°C

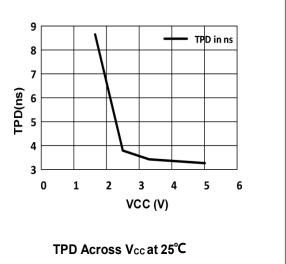
Parameter		Test Conditions	V <sub>CC</sub> =1.8V	Vcc=2.5V	Vcc=3.3V	Units
		Typ		Тур	Тур	UIIILS
C <sub>pd</sub>	Power Dissipation Capacitance	f=10Mhz	20	20	20	pF



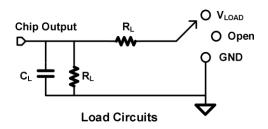
# **Typical Characteristics**

Typical values are at TA=+25°C (unless otherwise noted)





# **Parameter Measurement Information**

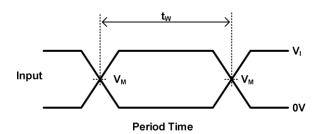


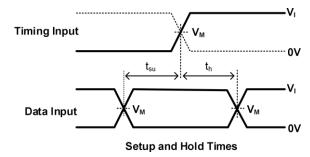
TEST	S1
T <sub>PHL</sub> /T <sub>PLH</sub>	OPEN
T <sub>PLZ</sub> /T <sub>PZL</sub>	$V_{LOAD}$
T <sub>PHZ</sub> /T <sub>PZH</sub>	GND

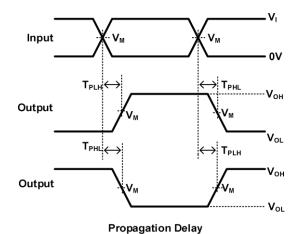
Vcc	Inputs		V <sub>M</sub>	$V_{LOAD}$	G	R∟	VΔ	
VCC	Vı	T <sub>f</sub> /T <sub>f</sub>	VIVI	VM VLOAD GL		V LOAD   OL   NL		VΔ
1.8V±0.15V	Vcc	≤2ns	Vcc/2	2×Vcc	15pF	1ΜΩ	0.15V	
2.5V±0.15V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	15pF	1ΜΩ	0.15V	
3.3V±0.15V	3V	≤2.5ns	1.5V	6V	15pF	1ΜΩ	0.3V	
5V±0.15V	Vcc	≤2.5ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	15pF	1ΝΩ	0.3V	



# **Parameter Measurement Information(Continued)**







En Input T<sub>PZL</sub> V<sub>LOAD</sub>/2 Output Waveform1  $V_{OL}$  $\mathsf{T}_{\mathsf{PZH}} \longleftrightarrow$  $T_{\text{PHZ}}$  $V_{OH}$  $V_{OH}$ - $V_{\Delta}$ Output Waveform2  $\approx 0 V$ 

**Enable and Disable Times** Low-And High-Level Enabling

Notes:A. C<sub>L</sub> includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.

for Output and Inverted Output

- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.

Waveform 2 is for an output with internal conditions such that the F. tpz\_ and tpz\_H are the same as ten. output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR 10 MHz, Z =50.

- G.  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  are the same as  $t_{\text{pd.}}$ 
  - H. All parameters and waveforms are not applicable to all device.

#### **Feature Description**

The SN74LVC1G86 device performs the Boolean function Y = AB + AB in positive logic. This single 2-input exclusive-OR gate is designed for 1.65V to 5.5V Vcc operation.

A common application is as a true and complement element. If the input is low, the other input is reproduced in true form at the output. If the input is high, the signal on the other input is reproduced inverted at the output.

This device is fully specified for partial-power-down applications using loff. The loff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

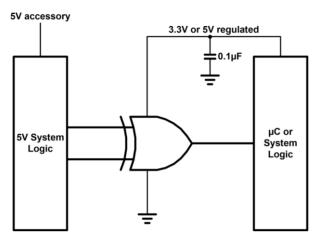
#### **Device Functional Modes**

Inputs		Output
Α	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L



# **Application Information**

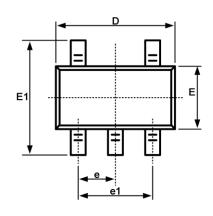
The SN74LVC1G86 device can accept input voltages up to 5.5 V at any valid Vcc which makes the device suitable for down translation. This feature of the SN74LVC1G86 makes it ideal for various bus interface applications.

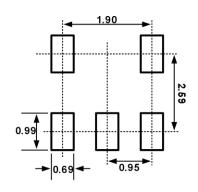


This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

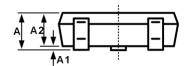


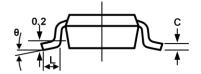
# Package Outline SOT23-5





Recommended Land Pattern (Unit: mm)

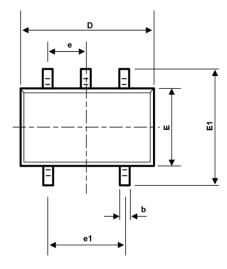


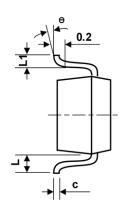


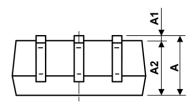
Cumbal	Dimensions	In Millimeters	Dimension	s In Inches
Symbol	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950	OBSC	0.037	7BSC
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
L1	0.60	OOREF		IREF
θ	0°	8°	0°	8°



# Package Outline SC70-5







symbol	Dimension In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
Α	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
С	0.110	0.175	0.004	0.007
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
е	0.650TYP		0.026TYP	
e1	1.200	1.400	0.047	0.055
L	0.525REF		0.021REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°



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